# NCE P-Channel Enhancement Mode Power MOSFET

### **Description**

The NCE3417 uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.

#### **General Features**

•  $V_{DS} = -12V, I_D = -4.4A$ 

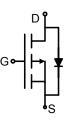
 $R_{DS(ON)}$  < 56m $\Omega$  @  $V_{GS}$ =-2.5V

 $R_{DS(ON)}$  < 40m $\Omega$  @  $V_{GS}$ =-4.5V

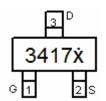
- High power and current handing capability
- Lead free product is acquired
- Surface mount package

# **Application**

- PWM applications
- Load switch
- Power management



Schematic diagram



Marking and pin Assignment



SOT-23 top view

### **Package Marking And Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
3417 X	NCE3417	SOT-23	Ø180mm	8 mm	3000 units

### Absolute Maximum Ratings (TA=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V <sub>DS</sub>	-12	V	
Gate-Source Voltage	V <sub>G</sub> S	±12	V	
Drain Current -Continuous	I <sub>D</sub>	-4.4	Α	
Drain Current -Pulsed (Note 1)	I <sub>DM</sub>	-15	Α	
Maximum Power Dissipation	P <sub>D</sub>	1.8	W	
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 150	$^{\circ}$ C	

### **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	R <sub>θJA</sub>	69	°C/W
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# Electrical Characteristics (T<sub>A</sub>=25 $^{\circ}$ C unless otherwise noted)

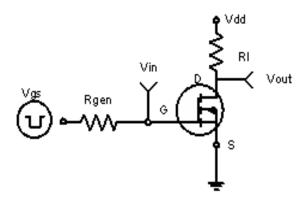
Parameter Symbol		Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-12		-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-12V,V <sub>GS</sub> =0V	-	-	-1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±12V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250μA	-0.45	-0.7	-1.0	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-4.4 A	-	27	40	mΩ
Diam-Source On-State Resistance		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-3A	-	40	56	
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-5V,I <sub>D</sub> =-4.4A	-	6	-	S
Dynamic Characteristics (Note4)			•			
Input Capacitance	C <sub>lss</sub>	V <sub>DS</sub> =-6V,V <sub>GS</sub> =0V,	-	700	-	PF
Output Capacitance	Coss	V <sub>DS</sub> 0V, V <sub>GS</sub> 0V,	-	280	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F-1.UIVINZ	-	210	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	13	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =-6 $V$ , $I_{D}$ =-4.4 $A$ ,	-	36	-	nS
Turn-Off Delay Time	$t_{d(off)}$	$R_L$ =-1.2 $\Omega$ , $V_{GEN}$ =-4.5 $V$ , $R_g$ =1 $\Omega$	-	32	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	12	-	nS
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-6V,I <sub>D</sub> =-4.4	-	8.1	-	nC
Gate-Source Charge	$Q_{gs}$	A.V <sub>GS</sub> =-4.5V	-	1.3	-	nC
Gate-Drain Charge	$Q_{gd}$	A, v GS4.5 v	-	1.7	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-4.4A	-	-	-1.2	V
Diode Forward Current (Note 2)	Is		-	-	4.4	Α

### Notes:

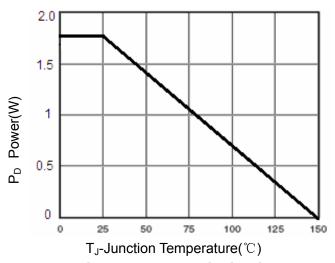
- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- **2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.
- 3. Pulse Test: Pulse Width ≤ 300 $\mu$ s, Duty Cycle ≤ 2%.
- **4.** Guaranteed by design, not subject to production



# **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Power Dissipation** 

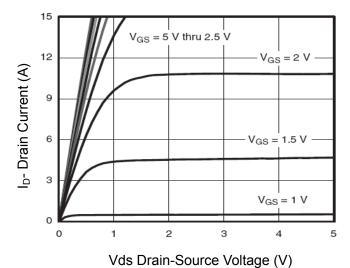


Figure 5 Output Characteristics

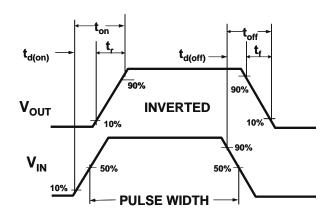
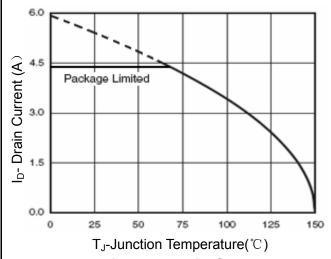


Figure 2:Switching Waveforms



**Figure 4 Drain Current** 

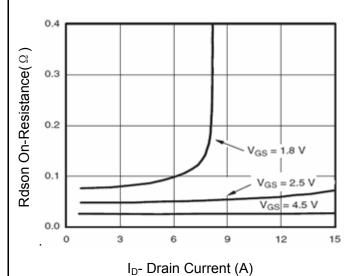
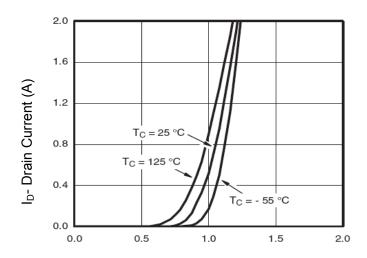


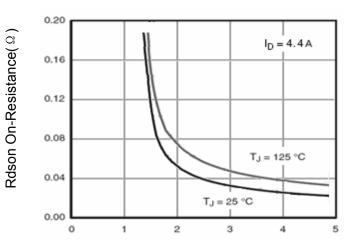
Figure 6 Drain-Source On-Resistance





Vgs Gate-Source Voltage (V)

**Figure 7 Transfer Characteristics** 



Vgs Gate-Source Voltage (V)

Figure 9 Rdson vs Vgs

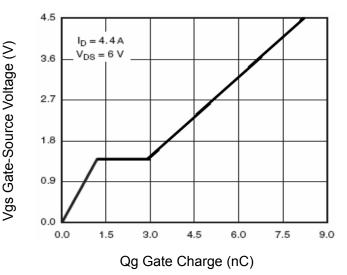


Figure 11 Gate Charge

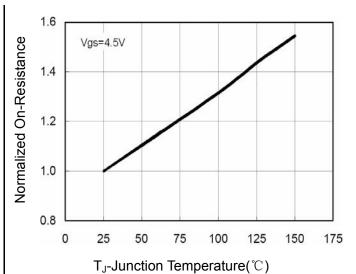
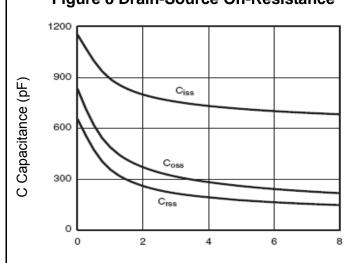
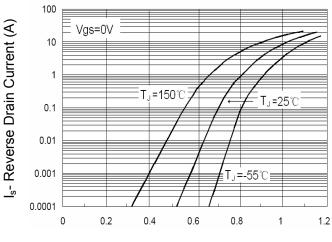


Figure 8 Drain-Source On-Resistance



Vds Drain-Source Voltage (V)

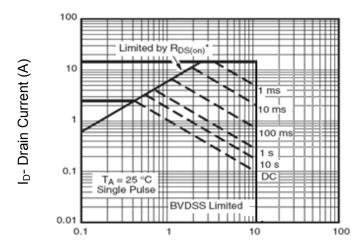
Figure 10 Capacitance vs Vds



Vsd Source-Drain Voltage (V)

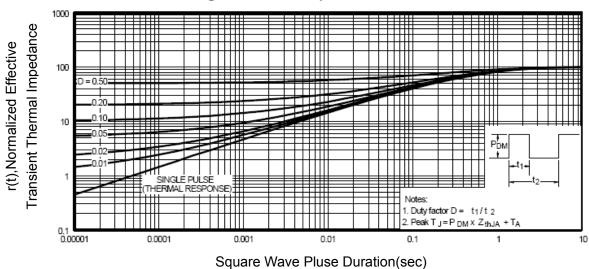
Figure 12 Source- Drain Diode Forward





Vds Drain-Source Voltage (V)

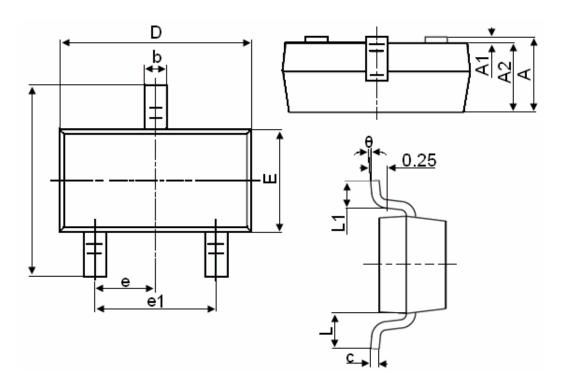
**Figure 13 Safe Operation Area** 



**Figure 14 Normalized Maximum Transient Thermal Impedance** 



# **SOT-23 Package Information**



Symbol	Dimensions in Millimeters				
	MIN.	MAX.			
А	0.900	1.150			
A1	0.000	0.100			
A2	0.900	1.050			
b	0.300	0.500			
С	0.080	0.150			
D	2.800	3.000			
Е	1.200	1.400			
E1	2.250	2.550			
е	0.950TYP				
e1	1.800	2.000			
L	0.550REF				
L1	0.300	0.500			
θ	0°	8°			

### **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$



### http://www.ncepower.com

NCE3417

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